Unit: mm

TOSHIBA Insulated Gate Bipolar Transistor Silicon N Channel IGBT

## GT50J121

# High Power Switching Applications Fast Switching Applications

- The 4th generation
- Enhancement-mode
- Fast switching (FS): Operating frequency up to 50 kHz (reference)
  - High speed:  $t_f = 0.05 \mu s$  (typ.)
  - Low switching loss:  $E_{0n} = 1.30 \text{ mJ (typ.)}$

 $: E_{off} = 1.34 \text{ mJ (typ.)}$ 

• Low saturation Voltage: VCE (sat) = 2.0 V (typ.)

### **Maximum Ratings (Ta = 25°C)**

| Characteristics                         |      | Symbol           | Rating     | Unit |  |
|---|------|------------------|------------|------|--|
| Collector-emitter voltage               |      | V <sub>CES</sub> | 600        | V    |  |
| Gate-emitter voltage                    |      | V <sub>GES</sub> | ±20        | ٧    |  |
| Collector current                       | DC   | Ic               | 50         | Α    |  |
|   | 1 ms | I <sub>CP</sub>  | 100        |      |  |
| Collector power dissipation (Tc = 25°C) |      | PC               | 240        | W    |  |
| Junction temperature                    |      | Tj               | 150        | °C   |  |
| Storage temperature range               |      | T <sub>stg</sub> | -55 to 150 | °C   |  |

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Weight: 9.75 g

#### **Thermal Characteristics**

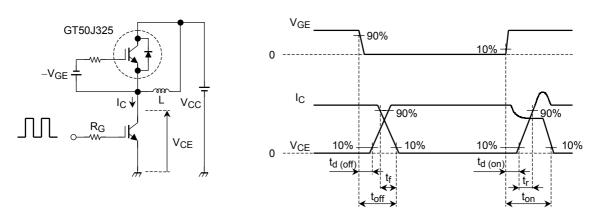
| Characteristics    | Symbol                | Max   | Unit |
|--------------------|-----------------------|-------|------|
| Thermal resistance | R <sub>th (j-c)</sub> | 0.521 | °C/W |

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### **Electrical Characteristics (Ta = 25°C)**

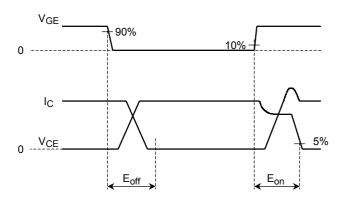
| Cha               | racteristics            | Symbol                | Test Condition  | Min | Тур. | Max  | Unit         |
|-------------------|-------------------------|-----------------------|---|-----|------|------|--------------|
| Gate leakage cu   | ırrent                  | I <sub>GES</sub>      | $V_{GE} = \pm 20 \text{ V}, V_{CE} = 0$   | _   | _    | ±500 | nA           |
| Collector cut-off | current                 | I <sub>CES</sub>      | V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0  | _   | _    | 1.0  | mA           |
| Gate-emitter cut  | t-off voltage           | V <sub>GE</sub> (OFF) | $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$  | 3.5 | _    | 6.5  | V            |
| Collector-emitte  | r saturation voltage    | V <sub>CE</sub> (sat) | I <sub>C</sub> = 50 A, V <sub>GE</sub> = 15 V   | _   | 2.0  | 2.45 | V            |
| Input capacitance |                         | C <sub>ies</sub>      | $V_{CE} = 10 \text{ V}, V_{GE} = 0, f = 1 \text{ MHz}$  | _   | 7900 | _    | pF           |
| Switching time    | Turn-on delay time      | t <sub>d (on)</sub>   | Inductive load $V_{CC}=300 \text{ V, } I_{C}=50 \text{ A}$ $V_{GG}=+15 \text{ V, } R_{G}=13 \Omega} \tag{Note 1)}$ (Note 2) | _   | 0.09 | _    | - μ <b>s</b> |
|                   | Rise time               | t <sub>r</sub>        |   | _   | 0.07 | _    |              |
|                   | Turn-on time            | t <sub>on</sub>       |   | _   | 0.24 | _    |              |
|                   | Turn-off delay time     | t <sub>d (off)</sub>  |   | _   | 0.30 | _    |              |
|                   | Fall time               | t <sub>f</sub>        |   | _   | 0.05 | _    |              |
|                   | Turn-off time           | t <sub>off</sub>      |   | _   | 0.43 | _    |              |
| Switching loss    | Turn-on switching loss  | E <sub>on</sub>       |   | _   | 1.30 | _    | - mJ         |
|                   | Turn-off switching loss | E <sub>off</sub>      |   |     | 1.34 | _    |              |

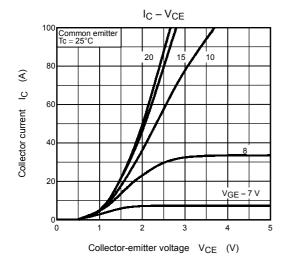
Note 1: Switching time measurement circuit and input/output waveforms

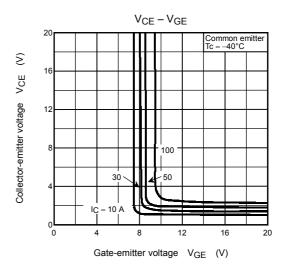


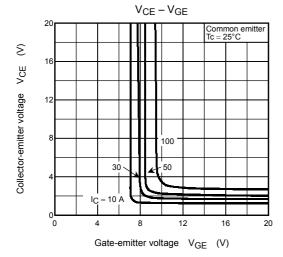
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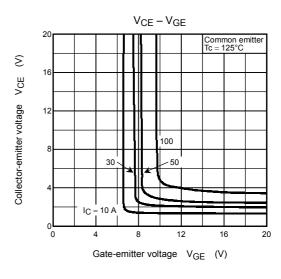
Note 2: Switching loss measurement waveforms

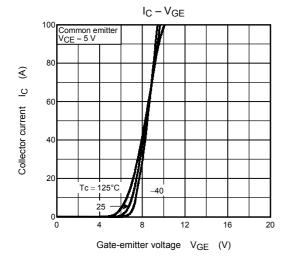


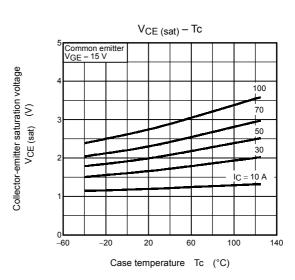


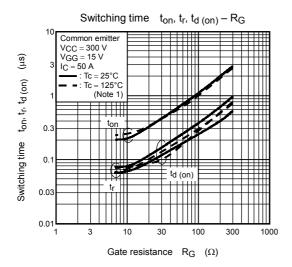


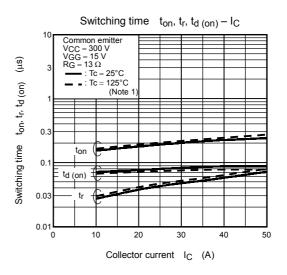


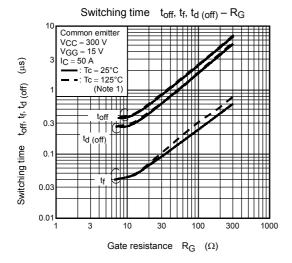


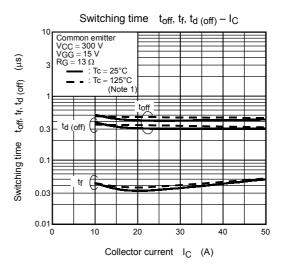


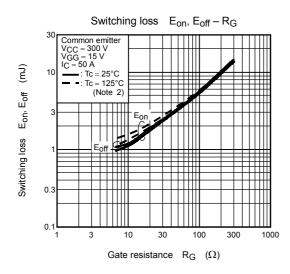


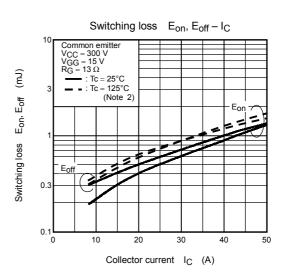




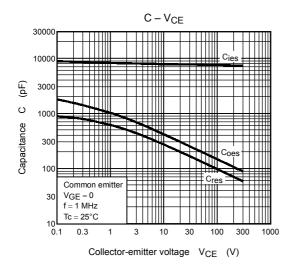


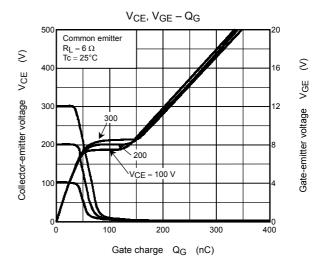


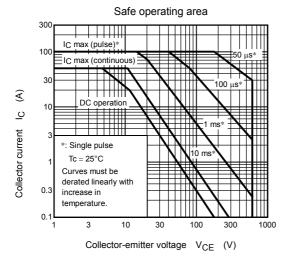


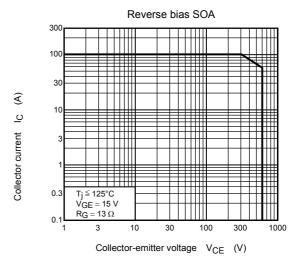


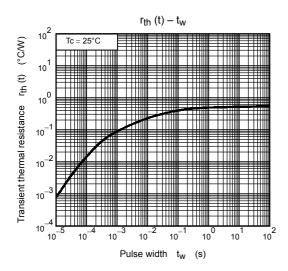
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